

● FEATURES:

Power dissipation

 P_D: 200 mW (T_{amb}=25°C)

Collector current

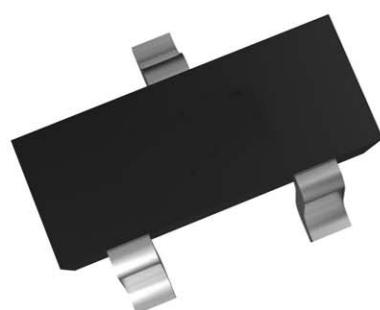
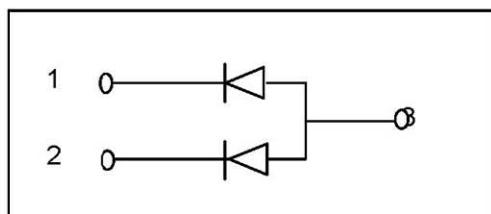
 I_F: 30 mA

Collector-base voltage

 V_R: 40 V

Operating and storage junction temperature range

 T_J, T_{stg}: -55°C to +150°C

SOT-323

CIRCUIT:

MARKING: 3E
● ELECTRICAL CHARACTERISTICS (T_{amb}=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Reverse breakdown voltage	V _(BR)	I _R = 100µA	40		V
Reverse voltage leakage current	I _R	V _R =10V		1	µA
Forward voltage	V _F	I _F =1mA		0.37	V
Diode capacitance	C _D	V _R =1V, f=1MHz		5	pF

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